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**Understanding Embedded - FPGAs (Field Programmable Gate Array)** 

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

## **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	384
Number of Logic Elements/Cells	1728
Total RAM Bits	32768
Number of I/O	180
Number of Gates	57906
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-BBGA
Supplier Device Package	256-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv50-6bg256c

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



## **Virtex Architecture**

Virtex devices feature a flexible, regular architecture that comprises an array of configurable logic blocks (CLBs) surrounded by programmable input/output blocks (IOBs), all interconnected by a rich hierarchy of fast, versatile routing resources. The abundance of routing resources permits the Virtex family to accommodate even the largest and most complex designs.

Virtex FPGAs are SRAM-based, and are customized by loading configuration data into internal memory cells. In some modes, the FPGA reads its own configuration data from an external PROM (master serial mode). Otherwise, the configuration data is written into the FPGA (Select-MAP<sup>TM</sup>, slave serial, and JTAG modes).

The standard Xilinx Foundation™ and Alliance Series™ Development systems deliver complete design support for Virtex, covering every aspect from behavioral and schematic entry, through simulation, automatic design translation and implementation, to the creation, downloading, and readback of a configuration bit stream.

## **Higher Performance**

Virtex devices provide better performance than previous generations of FPGA. Designs can achieve synchronous system clock rates up to 200 MHz including I/O. Virtex inputs and outputs comply fully with PCI specifications, and interfaces can be implemented that operate at 33 MHz or 66 MHz. Additionally, Virtex supports the hot-swapping requirements of Compact PCI.

Xilinx thoroughly benchmarked the Virtex family. While performance is design-dependent, many designs operated internally at speeds in excess of 100 MHz and can achieve 200 MHz. Table 2 shows performance data for representative circuits, using worst-case timing parameters.

Table 2: Performance for Common Circuit Functions

Function	Bits	Virtex -6
Register-to-Register		
Adder	16	5.0 ns
Audei	64	7.2 ns
Pipelined Multiplier	8 x 8	5.1 ns
	16 x 16	6.0 ns
Address Decoder	16	4.4 ns
	64	6.4 ns
16:1 Multiplexer		5.4 ns
Parity Tree	9	4.1 ns
	18	5.0 ns
	36	6.9 ns
Chip-to-Chip		
HSTL Class IV		200 MHz
LVTTL,16mA, fast slew		180 MHz

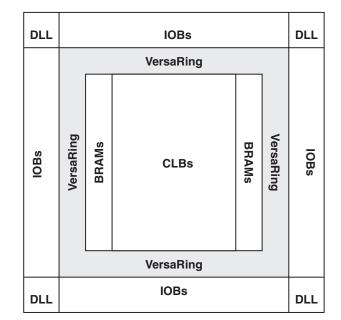


DS003-2 (v4.0) March 1, 2013

# Virtex<sup>™</sup> 2.5 V Field Programmable Gate Arrays

#### **Product Specification**

The output buffer and all of the IOB control signals have independent polarity controls.



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Figure 1: Virtex Architecture Overview

All pads are protected against damage from electrostatic discharge (ESD) and from over-voltage transients. Two forms of over-voltage protection are provided, one that permits 5 V compliance, and one that does not. For 5 V compliance, a Zener-like structure connected to ground turns on when the output rises to approximately 6.5 V. When PCI 3.3 V compliance is required, a conventional clamp diode is connected to the output supply voltage,  $V_{\rm CCO}$ .

Optional pull-up and pull-down resistors and an optional weak-keeper circuit are attached to each pad. Prior to configuration, all pins not involved in configuration are forced into their high-impedance state. The pull-down resistors and the weak-keeper circuits are inactive, but inputs can optionally be pulled up.

The activation of pull-up resistors prior to configuration is controlled on a global basis by the configuration mode pins. If the pull-up resistors are not activated, all the pins will float. Consequently, external pull-up or pull-down resistors must be provided on pins required to be at a well-defined logic level prior to configuration.

All Virtex IOBs support IEEE 1149.1-compatible boundary scan testing.

# **Architectural Description**

## **Virtex Array**

The Virtex user-programmable gate array, shown in Figure 1, comprises two major configurable elements: configurable logic blocks (CLBs) and input/output blocks (IOBs).

- CLBs provide the functional elements for constructing logic
- IOBs provide the interface between the package pins and the CLBs

CLBs interconnect through a general routing matrix (GRM). The GRM comprises an array of routing switches located at the intersections of horizontal and vertical routing channels. Each CLB nests into a VersaBlock™ that also provides local routing resources to connect the CLB to the GRM.

The VersaRing<sup>™</sup> I/O interface provides additional routing resources around the periphery of the device. This routing improves I/O routability and facilitates pin locking.

The Virtex architecture also includes the following circuits that connect to the GRM.

- Dedicated block memories of 4096 bits each
- Clock DLLs for clock-distribution delay compensation and clock domain control
- 3-State buffers (BUFTs) associated with each CLB that drive dedicated segmentable horizontal routing resources

Values stored in static memory cells control the configurable logic elements and interconnect resources. These values load into the memory cells on power-up, and can reload if necessary to change the function of the device.

## Input/Output Block

The Virtex IOB, Figure 2, features SelectIO™ inputs and outputs that support a wide variety of I/O signalling standards, see Table 1.

The three IOB storage elements function either as edge-triggered D-type flip-flops or as level sensitive latches. Each IOB has a clock signal (CLK) shared by the three flip-flops and independent clock enable signals for each flip-flop.

In addition to the CLK and CE control signals, the three flip-flops share a Set/Reset (SR). For each flip-flop, this signal can be independently configured as a synchronous Set, a synchronous Reset, an asynchronous Preset, or an asynchronous Clear.

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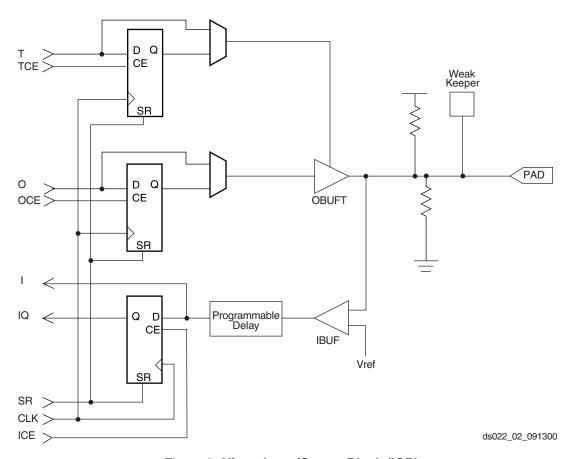


Figure 2: Virtex Input/Output Block (IOB)

Table 1: Supported Select I/O Standards

I/O Standard	Input Reference Voltage (V <sub>REF</sub> )	Output Source Voltage (V <sub>CCO</sub> )	Board Termination Voltage (V <sub>TT</sub> )	5 V Tolerant
LVTTL 2 – 24 mA	N/A	3.3	N/A	Yes
LVCMOS2	N/A	2.5	N/A	Yes
PCI, 5 V	N/A	3.3	N/A	Yes
PCI, 3.3 V	N/A	3.3	N/A	No
GTL	0.8	N/A	1.2	No
GTL+	1.0	N/A	1.5	No
HSTL Class I	0.75	1.5	0.75	No
HSTL Class III	0.9	1.5	1.5	No
HSTL Class IV	0.9	1.5	1.5	No
SSTL3 Class I &II	1.5	3.3	1.5	No
SSTL2 Class I & II	1.25	2.5	1.25	No
CTT	1.5	3.3	1.5	No
AGP	1.32	3.3	N/A	No



#### Input Path

A buffer In the Virtex IOB input path routes the input signal either directly to internal logic or through an optional input flip-flop.

An optional delay element at the D-input of this flip-flop eliminates pad-to-pad hold time. The delay is matched to the internal clock-distribution delay of the FPGA, and when used, assures that the pad-to-pad hold time is zero.

Each input buffer can be configured to conform to any of the low-voltage signalling standards supported. In some of these standards the input buffer utilizes a user-supplied threshold voltage, V<sub>REF</sub>. The need to supply V<sub>REF</sub> imposes constraints on which standards can used in close proximity to each other. See I/O Banking, page 3.

There are optional pull-up and pull-down resistors at each user I/O input for use after configuration. Their value is in the range 50 k $\Omega$  – 100 k $\Omega$ .

#### **Output Path**

The output path includes a 3-state output buffer that drives the output signal onto the pad. The output signal can be routed to the buffer directly from the internal logic or through an optional IOB output flip-flop.

The 3-state control of the output can also be routed directly from the internal logic or through a flip-flip that provides synchronous enable and disable.

Each output driver can be individually programmed for a wide range of low-voltage signalling standards. Each output buffer can source up to 24 mA and sink up to 48mA. Drive strength and slew rate controls minimize bus transients.

In most signalling standards, the output High voltage depends on an externally supplied  $V_{CCO}$  voltage. The need to supply  $V_{CCO}$  imposes constraints on which standards can be used in close proximity to each other. See **I/O Banking**, page 3.

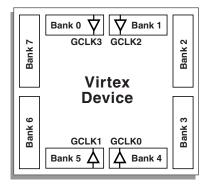
An optional weak-keeper circuit is connected to each output. When selected, the circuit monitors the voltage on the pad and weakly drives the pin High or Low to match the input signal. If the pin is connected to a multiple-source signal, the weak keeper holds the signal in its last state if all drivers are disabled. Maintaining a valid logic level in this way eliminates bus chatter.

Because the weak-keeper circuit uses the IOB input buffer to monitor the input level, an appropriate  $V_{\text{REF}}$  voltage must be provided if the signalling standard requires one. The provision of this voltage must comply with the I/O banking rules.

#### I/O Banking

Some of the I/O standards described above require  $V_{CCO}$  and/or  $V_{REF}$  voltages. These voltages externally and connected to device pins that serve groups of IOBs, called banks. Consequently, restrictions exist about which I/O standards can be combined within a given bank.

Eight I/O banks result from separating each edge of the FPGA into two banks, as shown in Figure 3. Each bank has multiple  $V_{\rm CCO}$  pins, all of which must be connected to the same voltage. This voltage is determined by the output standards in use.



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Figure 3: Virtex I/O Banks

Within a bank, output standards can be mixed only if they use the same  $V_{CCO}$ . Compatible standards are shown in Table 2. GTL and GTL+ appear under all voltages because their open-drain outputs do not depend on  $V_{CCO}$ .

Table 2: Compatible Output Standards

V <sub>CCO</sub>	Compatible Standards
3.3 V	PCI, LVTTL, SSTL3 I, SSTL3 II, CTT, AGP, GTL, GTL+
2.5 V	SSTL2 I, SSTL2 II, LVCMOS2, GTL, GTL+
1.5 V	HSTL I, HSTL III, HSTL IV, GTL, GTL+

Some input standards require a user-supplied threshold voltage,  $V_{REF}$  In this case, certain user-I/O pins are automatically configured as inputs for the  $V_{REF}$  voltage. Approximately one in six of the I/O pins in the bank assume this role

The  $V_{REF}$  pins within a bank are interconnected internally and consequently only one  $V_{REF}$  voltage can be used within each bank. All  $V_{REF}$  pins in the bank, however, must be connected to the external voltage source for correct operation.

Within a bank, inputs that require  $V_{REF}$  can be mixed with those that do not. However, only one  $V_{REF}$  voltage can be used within a bank. Input buffers that use  $V_{REF}$  are not 5 V tolerant. LVTTL, LVCMOS2, and PCI 33 MHz 5 V, are 5 V tolerant.

The  $V_{CCO}$  and  $V_{REF}$  pins for each bank appear in the device Pinout tables and diagrams. The diagrams also show the bank affiliation of each I/O.

Within a given package, the number of  $V_{REF}$  and  $V_{CCO}$  pins can vary depending on the size of device. In larger devices,



Each block SelectRAM cell, as illustrated in Figure 6, is a fully synchronous dual-ported 4096-bit RAM with independent control signals for each port. The data widths of the two ports can be configured independently, providing built-in bus-width conversion.

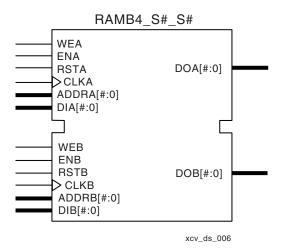


Figure 6: Dual-Port Block SelectRAM

Table 4 shows the depth and width aspect ratios for the block SelectRAM.

Table 4: Block SelectRAM Port Aspect Ratios

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

The Virtex block SelectRAM also includes dedicated routing to provide an efficient interface with both CLBs and other block SelectRAMs. Refer to XAPP130 for block SelectRAM timing waveforms.

## **Programmable Routing Matrix**

It is the longest delay path that limits the speed of any worst-case design. Consequently, the Virtex routing architecture and its place-and-route software were defined in a single optimization process. This joint optimization minimizes long-path delays, and consequently, yields the best system performance.

The joint optimization also reduces design compilation times because the architecture is software-friendly. Design cycles are correspondingly reduced due to shorter design iteration times.

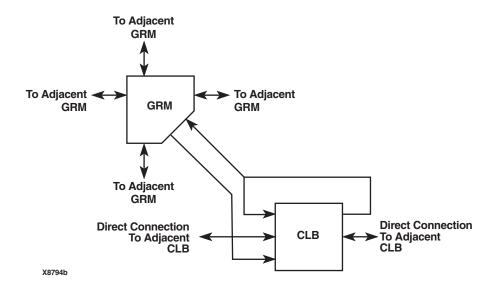


Figure 7: Virtex Local Routing

## **Local Routing**

The VersaBlock provides local routing resources, as shown in Figure 7, providing the following three types of connections.

- Interconnections among the LUTs, flip-flops, and GRM
- Internal CLB feedback paths that provide high-speed connections to LUTs within the same CLB, chaining them together with minimal routing delay
- Direct paths that provide high-speed connections between horizontally adjacent CLBs, eliminating the delay of the GRM.



Four dedicated clock pads are provided, one adjacent to each of the global buffers. The input to the global buffer is selected either from these pads or from signals in the general purpose routing.

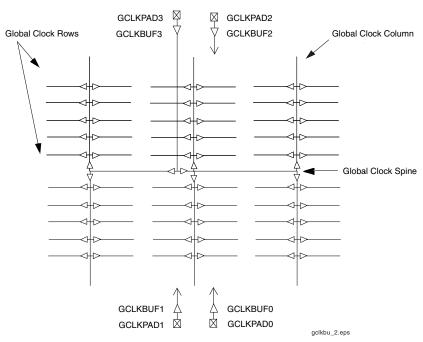


Figure 9: Global Clock Distribution Network

#### Delay-Locked Loop (DLL)

Associated with each global clock input buffer is a fully digital Delay-Locked Loop (DLL) that can eliminate skew between the clock input pad and internal clock-input pins throughout the device. Each DLL can drive two global clock networks. The DLL monitors the input clock and the distributed clock, and automatically adjusts a clock delay element. Clock edges reach internal flip-flops one to four clock periods after they arrive at the input. This closed-loop system effectively eliminates clock-distribution delay by ensuring that clock edges arrive at internal flip-flops in synchronism with clock edges arriving at the input.

In addition to eliminating clock-distribution delay, the DLL provides advanced control of multiple clock domains. The DLL provides four quadrature phases of the source clock, can double the clock, or divide the clock by 1.5, 2, 2.5, 3, 4, 5, 8, or 16.

The DLL also operates as a clock mirror. By driving the output from a DLL off-chip and then back on again, the DLL can be used to de-skew a board level clock among multiple Virtex devices.

In order to guarantee that the system clock is operating correctly prior to the FPGA starting up after configuration, the DLL can delay the completion of the configuration process until after it has achieved lock.

See **DLL Timing Parameters**, page 21 of Module 3, for frequency range information.

## **Boundary Scan**

Virtex devices support all the mandatory boundary-scan instructions specified in the IEEE standard 1149.1. A Test Access Port (TAP) and registers are provided that implement the EXTEST, INTEST, SAMPLE/PRELOAD, BYPASS, IDCODE, USERCODE, and HIGHZ instructions. The TAP also supports two internal scan chains and configuration/readback of the device.The TAP uses dedicated package pins that always operate using LVTTL. For TDO to operate using LVTTL, the  $\rm V_{CCO}$  for Bank 2 should be 3.3 V. Otherwise, TDO switches rail-to-rail between ground and  $\rm V_{CCO}$ .

Boundary-scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including un-bonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections, provided the user design or application is turned off.

Table 5 lists the boundary-scan instructions supported in Virtex FPGAs. Internal signals can be captured during EXTEST by connecting them to un-bonded or unused IOBs. They can also be connected to the unused outputs of IOBs defined as unidirectional input pins.

Before the device is configured, all instructions except USER1 and USER2 are available. After configuration, all instructions are available. During configuration, it is recommended that those operations using the boundary-scan register (SAMPLE/PRELOAD, INTEST, EXTEST) not be performed.



#### Master-Serial Mode

In master-serial mode, the CCLK output of the FPGA drives a Xilinx Serial PROM that feeds bit-serial data to the DIN input. The FPGA accepts this data on each rising CCLK edge. After the FPGA has been loaded, the data for the next device in a daisy-chain is presented on the DOUT pin after the rising CCLK edge.

The interface is identical to slave-serial except that an internal oscillator is used to generate the configuration clock (CCLK). A wide range of frequencies can be selected for CCLK which always starts at a slow default frequency. Configuration bits then switch CCLK to a higher frequency for the remainder of the configuration. Switching to a lower frequency is prohibited.

The CCLK frequency is set using the ConfigRate option in the bitstream generation software. The maximum CCLK frequency that can be selected is 60 MHz. When selecting a CCLK frequency, ensure that the serial PROM and any daisy-chained FPGAs are fast enough to support the clock rate.

On power-up, the CCLK frequency is 2.5 MHz. This frequency is used until the ConfigRate bits have been loaded when the frequency changes to the selected ConfigRate. Unless a different frequency is specified in the design, the default ConfigRate is 4 MHz.

Figure 12 shows a full master/slave system. In this system, the left-most device operates in master-serial mode. The remaining devices operate in slave-serial mode. The SPROM RESET pin is driven by  $\overline{\text{INIT}}$ , and the  $\overline{\text{CE}}$  input is driven by DONE. There is the potential for contention on the DONE pin, depending on the start-up sequence options chosen.

Figure 14 shows the timing of master-serial configuration. Master-serial mode is selected by a <000> or <100> on the mode pins (M2, M1, M0). Table 8 shows the timing information for Figure 14.

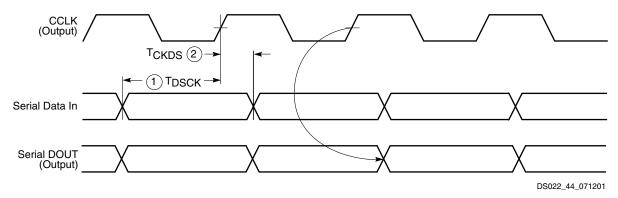


Figure 14: Master-Serial Mode Programming Switching Characteristics

At power-up,  $V_{CC}$  must rise from 1.0 V to  $V_{CC}$  min in less than 50 ms, otherwise delay configuration by pulling PROGRAM Low until  $V_{CC}$  is valid.

The sequence of operations necessary to configure a Virtex FPGA serially appears in Figure 15.

#### SelectMAP Mode

The SelectMAP mode is the fastest configuration option. Byte-wide data is written into the FPGA with a BUSY flag controlling the flow of data.

An external data source provides a byte stream, CCLK, a Chip Select  $(\overline{CS})$  signal and a Write signal  $(\overline{WRITE})$ . If BUSY is asserted (High) by the FPGA, the data must be held until BUSY goes Low.

Data can also be read using the SelectMAP mode. If WRITE is not asserted, configuration data is read out of the FPGA as part of a readback operation.

In the SelectMAP mode, multiple Virtex devices can be chained in parallel. DATA pins (D7:D0), CCLK, WRITE, BUSY, PROGRAM, DONE, and INIT can be connected in parallel between all the FPGAs. Note that the data is organized with the MSB of each byte on pin DO and the LSB of each byte on D7. The CS pins are kept separate, insuring that each FPGA can be selected individually. WRITE should be Low before loading the first bitstream and returned High after the last device has been programmed. Use  $\overline{\text{CS}}$  to select the appropriate FPGA for loading the bitstream and sending the configuration data. at the end of the bitstream, deselect the loaded device and select the next target FPGA by setting its  $\overline{\text{CS}}$  pin High. A free-running oscillator or other externally generated signal can be used for CCLK. The BUSY signal can be ignored for frequencies below 50 MHz. For details about frequencies above 50 MHz, see XAPP138, Virtex Configuration and Readback. Once all the devices have been programmed, the DONE pin goes High.



## Virtex<sup>™</sup> 2.5 V Field Programmable Gate Arrays

DS003-3 (v4.0) March 1, 2013

**Production Product Specification** 

# Virtex Electrical Characteristics Definition of Terms

Electrical and switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

**Advance**: These speed files are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

**Preliminary**: These speed files are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

**Production**: These speed files are released once enough production silicon of a particular device family member has been characterized to provide full correlation between speed files and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are representative of worst-case supply voltage and junction temperature conditions. The parameters included are common to popular designs and typical applications. Contact the factory for design considerations requiring more detailed information.

Table 1 correlates the current status of each Virtex device with a corresponding speed file designation.

Table 1: Virtex Device Speed Grade Designations

	Speed Grade Designations					
Device	Advance	Preliminary	Production			
XCV50			-6, -5, -4			
XCV100			-6, -5, -4			
XCV150			-6, -5, -4			
XCV200			-6, -5, -4			
XCV300			-6, -5, -4			
XCV400			-6, -5, -4			
XCV600			-6, -5, -4			
XCV800			-6, -5, -4			
XCV1000			-6, -5, -4			

All specifications are subject to change without notice.



## **Virtex DC Characteristics**

## **Absolute Maximum Ratings**

Symbol	Description <sup>(1)</sup>			Units
V <sub>CCINT</sub>	Supply voltage relative to GND <sup>(2)</sup>	Supply voltage relative to GND <sup>(2)</sup>		V
V <sub>CCO</sub>	Supply voltage relative to GND <sup>(2)</sup>	Supply voltage relative to GND <sup>(2)</sup>		V
V <sub>REF</sub>	Input Reference Voltage		-0.5 to 3.6	V
V	Input voltage relative to GND <sup>(3)</sup>	Using V <sub>REF</sub>	-0.5 to 3.6	V
V <sub>IN</sub>		Internal threshold	-0.5 to 5.5	V
V <sub>TS</sub>	Voltage applied to 3-state output		-0.5 to 5.5	V
V <sub>CC</sub>	Longest Supply Voltage Rise Time from 1V-2.375V		50	ms
T <sub>STG</sub>	Storage temperature (ambient)		-65 to +150	°C
TJ	Junction temperature <sup>(4)</sup>	Plastic Packages	+125	°C

#### Notes:

- Stresses beyond those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress
  ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions
  is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time can affect device reliability.
- 2. Power supplies can turn on in any order.
- 3. For protracted periods (e.g., longer than a day),  $V_{IN}$  should not exceed  $V_{CCO}$  by more than 3.6 V.
- 4. For soldering guidelines and thermal considerations, see the "Device Packaging" information on <a href="https://www.xilinx.com">www.xilinx.com</a>.

## **Recommended Operating Conditions**

Symbol	Description		Min	Max	Units
$V_{CCINT}^{(1)}$ Input Supply voltage relative to GND, $T_J = 0$ °C to +85		Commercial	2.5 – 5%	2.5 + 5%	V
CCINT` /	Input Supply voltage relative to GND, $T_J = -40^{\circ}\text{C}$ to $+100^{\circ}\text{C}$	Industrial	2.5 – 5%	2.5 + 5%	V
V <sub>CCO</sub> <sup>(4)</sup>	Supply voltage relative to GND, T <sub>J</sub> = 0 °C to +85°C	Commercial	1.4	3.6	V
, CCO,	Supply voltage relative to GND, T <sub>J</sub> = -40°C to +100°C Industrial		1.4	3.6	V
T <sub>IN</sub>	Input signal transition time			250	ns

- Correct operation is guaranteed with a minimum V<sub>CCINT</sub> of 2.375 V (Nominal V<sub>CCINT</sub> -5%). Below the minimum value, all delay parameters increase by 3% for each 50-mV reduction in V<sub>CCINT</sub> below the specified range.
- 2. At junction temperatures above those listed as Operating Conditions, delay parameters do increase. Please refer to the TRCE report.
- 3. Input and output measurement threshold is  $\sim$ 50% of  $V_{CC}$ .
- Min and Max values for V<sub>CCO</sub> are I/O Standard dependant.



## **DC Characteristics Over Recommended Operating Conditions**

Symbol	Description	1	Device	Min	Max	Units
V <sub>DRINT</sub>	Data Retention V <sub>CCINT</sub> Voltage		All	2.0		V
21	(below which configuration data can be	e lost)				
$V_{\mathrm{DRIO}}$	Data Retention V <sub>CCO</sub> Voltage (below which configuration data can be	e lost)	All	1.2		V
I <sub>CCINTQ</sub>	Quiescent V <sub>CCINT</sub> supply current <sup>(1,3)</sup>		XCV50		50	mA
			XCV100		50	mA
			XCV150		50	mA
			XCV200		75	mA
			XCV300		75	mA
			XCV400		75	mA
			XCV600		100	mA
			XCV800		100	mA
			XCV1000		100	mA
Iccoq	Quiescent V <sub>CCO</sub> supply current <sup>(1)</sup>		XCV50		2	mA
			XCV100		2	mA
			XCV150		2	mA
			XCV200		2	mA
			XCV300		2	mA
			XCV400		2	mA
			XCV600		2	mA
			XCV800		2	mA
			XCV1000		2	mA
I <sub>REF</sub>	V <sub>REF</sub> current per V <sub>REF</sub> pin		All		20	μΑ
ΙL	Input or output leakage current		All	-10	+10	μΑ
C <sub>IN</sub>	Input capacitance (sample tested)	BGA, PQ, HQ, packages	All		8	pF
I <sub>RPU</sub>	Pad pull-up (when selected) @ V <sub>in</sub> = 0 tested)	V, V <sub>CCO</sub> = 3.3 V (sample	All	Note (2)	0.25	mA
I <sub>RPD</sub>	Pad pull-down (when selected) @ V <sub>in</sub> =	= 3.6 V (sample tested)		Note (2)	0.15	mA

- 1. With no output current loads, no active input pull-up resistors, all I/O pins 3-stated and floating.
- 2. Internal pull-up and pull-down resistors guarantee valid logic levels at unconnected input pins. These pull-up and pull-down resistors do not guarantee valid logic levels when input pins are connected to other circuits.
- 3. Multiply I<sub>CCINTQ</sub> limit by two for industrial grade.



## **Virtex Switching Characteristics**

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE

in the Xilinx Development System) and back-annotated to the simulation net list. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Virtex devices unless otherwise noted.

## **IOB Input Switching Characteristics**

Input delays associated with the pad are specified for LVTTL levels. For other standards, adjust the delays with the values shown in , page 6.

				Speed	Grade		
Description	Device	Symbol	Min	-6	-5	-4	Units
Propagation Delays							
Pad to I output, no delay	All	T <sub>IOPI</sub>	0.39	0.8	0.9	1.0	ns, max
Pad to I output, with delay	XCV50	T <sub>IOPID</sub>	0.8	1.5	1.7	1.9	ns, max
	XCV100		0.8	1.5	1.7	1.9	ns, max
	XCV150		0.8	1.5	1.7	1.9	ns, max
	XCV200		0.8	1.5	1.7	1.9	ns, max
	XCV300		0.8	1.5	1.7	1.9	ns, max
	XCV400		0.9	1.8	2.0	2.3	ns, max
	XCV600		0.9	1.8	2.0	2.3	ns, max
	XCV800		1.1	2.1	2.4	2.7	ns, max
	XCV1000		1.1	2.1	2.4	2.7	ns, max
Pad to output IQ via transparent latch, no delay	All	T <sub>IOPLI</sub>	0.8	1.6	1.8	2.0	ns, max
Pad to output IQ via transparent	XCV50	T <sub>IOPLID</sub>	1.9	3.7	4.2	4.8	ns, max
latch, with delay	XCV100		1.9	3.7	4.2	4.8	ns, max
	XCV150		2.0	3.9	4.3	4.9	ns, max
	XCV200		2.0	4.0	4.4	5.1	ns, max
	XCV300		2.0	4.0	4.4	5.1	ns, max
	XCV400		2.1	4.1	4.6	5.3	ns, max
	XCV600		2.1	4.2	4.7	5.4	ns, max
	XCV800		2.2	4.4	4.9	5.6	ns, max
	XCV1000		2.3	4.5	5.1	5.8	ns, max
Sequential Delays			·				
Clock CLK	All						
Minimum Pulse Width, High		T <sub>CH</sub>	0.8	1.5	1.7	2.0	ns, min
Minimum Pulse Width, Low		T <sub>CL</sub>	0.8	1.5	1.7	2.0	ns, min
Clock CLK to output IQ		T <sub>IOCKIQ</sub>	0.2	0.7	0.7	8.0	ns, max



## **IOB Output Switching Characteristics Standard Adjustments**

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays by the values shown.

				Speed	Grade		Unit
Description	Symbol	Standard <sup>(1)</sup>	Min	-6	-5	-4	s
Output Delay Adjustments							
Standard-specific adjustments for	T <sub>OLVTTL_S2</sub>	LVTTL, Slow, 2 mA	4.2	14.7	15.8	17.0	ns
output delays terminating at pads (based on standard capacitive load,	T <sub>OLVTTL_S4</sub>	4 mA	2.5	7.5	8.0	8.6	ns
Csl)	T <sub>OLVTTL_S6</sub>	6 mA	1.8	4.8	5.1	5.6	ns
	T <sub>OLVTTL_S8</sub>	8 mA	1.2	3.0	3.3	3.5	ns
	T <sub>OLVTTL_S12</sub>	12 mA	1.0	1.9	2.1	2.2	ns
	T <sub>OLVTTL_S16</sub>	16 mA	0.9	1.7	1.9	2.0	ns
	T <sub>OLVTTL_S24</sub>	24 mA	0.8	1.3	1.4	1.6	ns
	T <sub>OLVTTL_F2</sub>	LVTTL, Fast, 2mA	1.9	13.1	14.0	15.1	ns
	T <sub>OLVTTL_F4</sub>	4 mA	0.7	5.3	5.7	6.1	ns
	T <sub>OLVTTL_F6</sub>	6 mA	0.2	3.1	3.3	3.6	ns
	T <sub>OLVTTL_F8</sub>	8 mA	0.1	1.0	1.1	1.2	ns
	T <sub>OLVTTL_F12</sub>	12 mA	0	0	0	0	ns
	T <sub>OLVTTL_F16</sub>	16 mA	-0.10	-0.05	-0.05	-0.05	ns
	T <sub>OLVTTL_F24</sub>	24 mA	-0.10	-0.20	-0.21	-0.23	ns
	T <sub>OLVCMOS2</sub>	LVCMOS2	0.10	0.10	0.11	0.12	ns
	T <sub>OPCl33_3</sub>	PCI, 33 MHz, 3.3 V	0.50	2.3	2.5	2.7	ns
	T <sub>OPCl33_5</sub>	PCI, 33 MHz, 5.0 V	0.40	2.8	3.0	3.3	ns
	T <sub>OPCI66_3</sub>	PCI, 66 MHz, 3.3 V	0.10	-0.40	-0.42	-0.46	ns
	T <sub>OGTL</sub>	GTL	0.6	0.50	0.54	0.6	ns
	T <sub>OGTLP</sub>	GTL+	0.7	0.8	0.9	1.0	ns
	T <sub>OHSTL_I</sub>	HSTL I	0.10	-0.50	-0.53	-0.5	ns
	T <sub>OHSTL_III</sub>	HSTL III	-0.10	-0.9	-0.9	-1.0	ns
	T <sub>OHSTL_IV</sub>	HSTL IV	-0.20	-1.0	-1.0	-1.1	ns
	T <sub>OSSTL2_I</sub>	SSTL2 I	-0.10	-0.50	-0.53	-0.5	ns
	T <sub>OSSLT2_II</sub>	SSTL2 II	-0.20	-0.9	-0.9	-1.0	ns
	T <sub>OSSTL3_I</sub>	SSTL3 I	-0.20	-0.50	-0.53	-0.5	ns
	T <sub>OSSTL3_II</sub>	SSTL3 II	-0.30	-1.0	-1.0	-1.1	ns
	T <sub>OCTT</sub>	СТТ	0	-0.6	-0.6	-0.6	ns
	T <sub>OAGP</sub>	AGP	0	-0.9	-0.9	-1.0	ns

<sup>1.</sup> Output timing is measured at 1.4 V with 35 pF external capacitive load for LVTTL. For other I/O standards and different loads, see Table 2 and Table 3.



## **Clock Distribution Guidelines**

			Sp	Speed Grade		
Description	Device	Symbol	-6	-5	-4	Units
Global Clock Skew <sup>(1)</sup>						
Global Clock Skew between IOB Flip-flops	XCV50	T <sub>GSKEWIOB</sub>	0.10	0.12	0.14	ns, max
	XCV100		0.12	0.13	0.15	ns, max
	XCV150		0.12	0.13	0.15	ns, max
	XCV200		0.13	0.14	0.16	ns, max
	XCV300		0.14	0.16	0.18	ns, max
	XCV400		0.13	0.13	0.14	ns, max
	XCV600		0.14	0.15	0.17	ns, max
	XCV800		0.16	0.17	0.20	ns, max
	XCV1000		0.20	0.23	0.25	ns, max

#### Notes:

## **Clock Distribution Switching Characteristics**

		Speed Grade				
Description	Symbol	Min	-6	<b>-</b> 5	-4	Units
GCLK IOB and Buffer						
Global Clock PAD to output.	T <sub>GPIO</sub>	0.33	0.7	0.8	0.9	ns, max
Global Clock Buffer I input to O output	T <sub>GIO</sub>	0.34	0.7	0.8	0.9	ns, max

<sup>1.</sup> These clock-skew delays are provided for guidance only. They reflect the delays encountered in a typical design under worst-case conditions. Precise values for a particular design are provided by the timing analyzer.



## **CLB SelectRAM Switching Characteristics**

			Speed Grade				
Description	Symbol	Min	-6	-5	-4	Units	
Sequential Delays							
Clock CLK to X/Y outputs (WE active) 16 x 1 mode	T <sub>SHCKO16</sub>	1.2	2.3	2.6	3.0	ns, max	
Clock CLK to X/Y outputs (WE active) 32 x 1 mode	T <sub>SHCKO32</sub>	1.2	2.7	3.1	3.5	ns, max	
Shift-Register Mode							
Clock CLK to X/Y outputs	T <sub>REG</sub>	1.2	3.7	4.1	4.7	ns, max	
Setup and Hold Times before/after Clock CLK <sup>(1)</sup>		Se	tup Time /	Hold Time	T.	·	
F/G address inputs	T <sub>AS</sub> /T <sub>AH</sub>	0.25 / 0	0.5 / 0	0.6 / 0	0.7 / 0	ns, min	
BX/BY data inputs (DIN)	T <sub>DS</sub> /T <sub>DH</sub>	0.34 / 0	0.7 / 0	0.8 / 0	0.9 / 0	ns, min	
CE input (WE)	T <sub>WS</sub> /T <sub>WH</sub>	0.38 / 0	0.8 / 0	0.9 / 0	1.0 / 0	ns, min	
Shift-Register Mode		·		,	1	·	
BX/BY data inputs (DIN)	T <sub>SHDICK</sub>	0.34	0.7	0.8	0.9	ns, min	
CE input (WS)	T <sub>SHCECK</sub>	0.38	0.8	0.9	1.0	ns, min	
Clock CLK		-			1	-	
Minimum Pulse Width, High	T <sub>WPH</sub>	1.2	2.4	2.7	3.1	ns, min	
Minimum Pulse Width, Low	T <sub>WPL</sub>	1.2	2.4	2.7	3.1	ns, min	
Minimum clock period to meet address write cycle time	T <sub>WC</sub>	2.4	4.8	5.4	6.2	ns, min	
Shift-Register Mode							
Minimum Pulse Width, High	T <sub>SRPH</sub>	1.2	2.4	2.7	3.1	ns, min	
Minimum Pulse Width, Low	T <sub>SRPL</sub>	1.2	2.4	2.7	3.1	ns, min	

<sup>1.</sup> A Zero "0" Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed "best-case", but if a "0" is listed, there is no positive hold time.



#### **Minimum Clock-to-Out for Virtex Devices**

	With DLL	Without DLL									
I/O Standard	All Devices	V50	V100	V150	V200	V300	V400	V600	V800	V1000	Units
*LVTTL_S2	5.2	6.0	6.0	6.0	6.0	6.1	6.1	6.1	6.1	6.1	ns
*LVTTL_S4	3.5	4.3	4.3	4.3	4.3	4.4	4.4	4.4	4.4	4.4	ns
*LVTTL_S6	2.8	3.6	3.6	3.6	3.6	3.7	3.7	3.7	3.7	3.7	ns
*LVTTL_S8	2.2	3.1	3.1	3.1	3.1	3.1	3.1	3.2	3.2	3.2	ns
*LVTTL_S12	2.0	2.9	2.9	2.9	2.9	2.9	2.9	3.0	3.0	3.0	ns
*LVTTL_S16	1.9	2.8	2.8	2.8	2.8	2.8	2.8	2.9	2.9	2.9	ns
*LVTTL_S24	1.8	2.6	2.6	2.7	2.7	2.7	2.7	2.7	2.7	2.8	ns
*LVTTL_F2	2.9	3.8	3.8	3.8	3.8	3.8	3.8	3.9	3.9	3.9	ns
*LVTTL_F4	1.7	2.6	2.6	2.6	2.6	2.6	2.6	2.7	2.7	2.7	ns
*LVTTL_F6	1.2	2.0	2.0	2.0	2.1	2.1	2.1	2.1	2.1	2.2	ns
*LVTTL_F8	1.1	1.9	1.9	1.9	1.9	2.0	2.0	2.0	2.0	2.0	ns
*LVTTL_F12	1.0	1.8	1.8	1.8	1.8	1.9	1.9	1.9	1.9	1.9	ns
*LVTTL_F16	0.9	1.7	1.8	1.8	1.8	1.8	1.8	1.8	1.9	1.9	ns
*LVTTL_F24	0.9	1.7	1.7	1.7	1.8	1.8	1.8	1.8	1.8	1.9	ns
LVCMOS2	1.1	1.9	1.9	1.9	2.0	2.0	2.0	2.0	2.0	2.1	ns
PCI33_3	1.5	2.4	2.4	2.4	2.4	2.4	2.4	2.5	2.5	2.5	ns
PCI33_5	1.4	2.2	2.2	2.3	2.3	2.3	2.3	2.3	2.3	2.4	ns
PCI66_3	1.1	1.9	1.9	2.0	2.0	2.0	2.0	2.0	2.1	2.1	ns
GTL	1.6	2.5	2.5	2.5	2.5	2.5	2.5	2.6	2.6	2.6	ns
GTL+	1.7	2.5	2.5	2.6	2.6	2.6	2.6	2.6	2.6	2.7	ns
HSTL I	1.1	1.9	1.9	1.9	1.9	2.0	2.0	2.0	2.0	2.0	ns
HSTL III	0.9	1.7	1.7	1.8	1.8	1.8	1.8	1.8	1.8	1.9	ns
HSTL IV	0.8	1.6	1.6	1.6	1.7	1.7	1.7	1.7	1.7	1.8	ns
SSTL2 I	0.9	1.7	1.7	1.7	1.7	1.8	1.8	1.8	1.8	1.8	ns
SSTL2 II	0.8	1.6	1.6	1.6	1.6	1.7	1.7	1.7	1.7	1.7	ns
SSTL3 I	0.8	1.6	1.7	1.7	1.7	1.7	1.7	1.7	1.8	1.8	ns
SSTL3 II	0.7	1.5	1.5	1.6	1.6	1.6	1.6	1.6	1.6	1.7	ns
CTT	1.0	1.8	1.8	1.8	1.9	1.9	1.9	1.9	1.9	2.0	ns
AGP	1.0	1.8	1.8	1.9	1.9	1.9	1.9	1.9	1.9	2.0	ns

<sup>\*</sup>S = Slow Slew Rate, F = Fast Slew Rate

<sup>1.</sup> Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

<sup>2.</sup> Input and output timing is measured at 1.4 V for LVTTL. For other I/O standards, see Table 3. In all cases, an 8 pF external capacitive load is used.



# Virtex<sup>™</sup> 2.5 V Field Programmable Gate Arrays

DS003-4 (v4.0) March 1, 2013

**Production Product Specification** 

## **Virtex Pin Definitions**

Table 1: Special Purpose Pins

Pin Name	Dedicated Pin	Direction	Description
GCK0, GCK1, GCK2, GCK3	Yes	Input	Clock input pins that connect to Global Clock Buffers. These pins become user inputs when not needed for clocks.
M0, M1, M2	Yes	Input	Mode pins are used to specify the configuration mode.
CCLK	Yes	Input or Output	The configuration Clock I/O pin: it is an input for SelectMAP and slave-serial modes, and output in master-serial mode. After configuration, it is input only, logic level = Don't Care.
PROGRAM	Yes	Input	Initiates a configuration sequence when asserted Low.
DONE	Yes	Bidirectional	Indicates that configuration loading is complete, and that the start-up sequence is in progress. The output can be open drain.
INIT	No	Bidirectional (Open-drain)	When Low, indicates that the configuration memory is being cleared. The pin becomes a user I/O after configuration.
BUSY/ DOUT	No	Output	In SelectMAP mode, BUSY controls the rate at which configuration data is loaded. The pin becomes a user I/O after configuration unless the SelectMAP port is retained.
			In bit-serial modes, DOUT provides header information to downstream devices in a daisy-chain. The pin becomes a user I/O after configuration.
D0/DIN, D1, D2, D3, D4, D5, D6,	No	Input or Output	In SelectMAP mode, D0 - D7 are configuration data pins. These pins become user I/Os after configuration unless the SelectMAP port is retained.  In bit-serial modes, DIN is the single data input. This pin becomes a user
D7			I/O after configuration.
WRITE	No	Input	In SelectMAP mode, the active-low Write Enable signal. The pin becomes a user I/O after configuration unless the SelectMAP port is retained.
CS	No	Input	In SelectMAP mode, the active-low Chip Select signal. The pin becomes a user I/O after configuration unless the SelectMAP port is retained.
TDI, TDO, TMS, TCK	Yes	Mixed	Boundary-scan Test-Access-Port pins, as defined in IEEE 1149.1.
DXN, DXP	Yes	N/A	Temperature-sensing diode pins. (Anode: DXP, cathode: DXN)
V <sub>CCINT</sub>	Yes	Input	Power-supply pins for the internal core logic.
V <sub>cco</sub>	Yes	Input	Power-supply pins for the output drivers (subject to banking rules)
V <sub>REF</sub>	No	Input	Input threshold voltage pins. Become user I/Os when an external threshold voltage is not needed (subject to banking rules).
GND	Yes	Input	Ground

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## **Virtex Pinout Information**

#### **Pinout Tables**

See <a href="https://www.xilinx.com">www.xilinx.com</a> for updates or additional pinout information. For convenience, Table 2, Table 3 and Table 4 list the locations of special-purpose and power-supply pins. Pins not listed are either user I/Os or not connected, depending on the device/package combination. See the Pinout Diagrams starting on page 17 for any pins not listed for a particular part/package combination.

Table 2: Virtex Pinout Tables (Chip-Scale and QFP Packages)

Pin Name	Device	CS144	TQ144	PQ/HQ240
GCK0	All	K7	90	92
GCK1	All	M7	93	89
GCK2	All	A7	19	210
GCK3	All	A6	16	213
MO	All	M1	110	60
M1	All	L2	112	58
M2	All	N2	108	62
CCLK	All	B13	38	179
PROGRAM	All	L12	72	122
DONE	All	M12	74	120
INIT	All	L13	71	123
BUSY/DOUT	All	C11	39	178
D0/DIN	All	C12	40	177
D1	All	E10	45	167
D2	All	E12	47	163
D3	All	F11	51	156
D4	All	H12	59	145
D5	All	J13	63	138
D6	All	J11	65	134
D7	All	K10	70	124
WRITE	All	C10	32	185
CS	All	D10	33	184
TDI	All	A11	34	183
TDO	All	A12	36	181
TMS	All	B1	143	2
TCK	All	C3	2	239
V <sub>CCINT</sub>	All	A9, B6, C5, G3, G12, M5, M9, N6	10, 15, 25, 57, 84, 94, 99, 126	16, 32, 43, 77, 88, 104, 137, 148, 164, 198, 214, 225



Table 4: Virtex Pinout Tables (Fine-Pitch BGA)

Pin Name	Device	FG256	FG456	FG676	FG680
GCK0	All	N8	W12	AA14	AW19
GCK1	All	R8	Y11	AB13	AU22
GCK2	All	C9	A11	C13	D21
GCK3	All	B8	C11	E13	A20
M0	All	N3	AB2	AD4	AT37
M1	All	P2	U5	W7	AU38
M2	All	R3	Y4	AB6	AT35
CCLK	All	D15	B22	D24	E4
PROGRAM	All	P15	W20	AA22	AT5
DONE	All	R14	Y19	AB21	AU5
INIT	All	N15	V19	Y21	AU2
BUSY/DOUT	All	C15	C21	E23	E3
D0/DIN	All	D14	D20	F22	C2
D1	All	E16	H22	K24	P4
D2	All	F15	H20	K22	P3
D3	All	G16	K20	M22	R1
D4	All	J16	N22	R24	AD3
D5	All	M16	R21	U23	AG2
D6	All	N16	T22	V24	AH1
D7	All	N14	Y21	AB23	AR4
WRITE	All	C13	A20	C22	B4
CS	All	B13	C19	E21	D5
TDI	All	A15	B20	D22	В3
TDO	All	B14	A21	C23	C4
TMS	All	D3	D3	F5	E36
TCK	All	C4	C4	E6	C36
DXN	All	R4	Y5	AB7	AV37
DXP	All	P4	V6	Y8	AU35



Table 4: Virtex Pinout Tables (Fine-Pitch BGA) (Continued)

Pin Name	Device	FG256	FG456	FG676	FG680
No Connect (No-connect pins are listed incrementally. All pins listed for both the required device and all larger devices listed in the same package are no connects.)	XCV800	N/A	N/A	A2, A3, A15, A25, B1, B6, B11, B16, B21, B24, B26, C1, C2, C25, C26, F2, F6, F21, F25, L2, L25, N25, P2, T2, T25, AA2, AA6, AA21, AA25, AD1, AD2, AD25, AE1, AE3, AE6, AE11, AE14, AE16, AE21, AE24, AE26, AF2, AF24, AF25	N/A
	XCV600	N/A	N/A	same as above	N/A
	XCV400	N/A	N/A	+ A9, A10, A13, A16, A24, AC1, AC25, AE12, AE15, AF3, AF10, AF11, AF13, AF14, AF16, AF18, AF23, B4, B12, B13, B15, B17, D1, D25, H26, J1, K26, L1, M1, M25, N1, N26, P1, P26, R2, R26, T1, T26, U26, V1	N/A
	XCV300	N/A	D4, D19, W4, W19	N/A	N/A
	XCV200	N/A	+ A2, A6, A12, B11, B16, C2, D1, D18, E17, E19, G2, G22, L2, L19, M2, M21, R3, R20, U3, U18, Y22, AA1, AA3, AA11, AA16, AB7, AB12, AB21,	N/A	N/A
	XCV150	N/A	+ A13, A14, C8, C9, E13, F11, H21, J1, J4, K2, K18, K19, M17, N1, P1, P5, P22, R22, W13, W15, AA9, AA10, AB8, AB14	N/A	N/A



## PQ240/HQ240 Pin Function Diagram

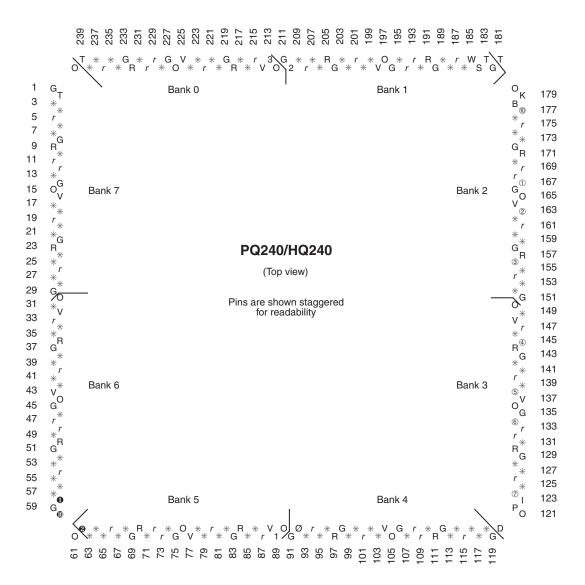


Figure 3: PQ240/HQ240 Pin Function Diagram